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Synthesis and photovoltaic properties of new europium complex Eu(DBM)₃(CPyBM)

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Abstract

A new europium(III) complex, tris(dibenzoylmethanate){1-[9-hexyl-9-carbazole]-2-(2-pyridyl)-benzimidazole}europium(III) [Eu(DBM)₃(CPyBM)] was synthesized and used as an electron-acceptor and electron-transport layer in organic photovoltaic (PV) device. Power conversion efficiency achieved from the device was 1.04% under illumination with 365 nm UV light at 1.6 mW/cm². Compared with the previous reported devices based on Eu(III) complexes, the PV performances were improved. The working mechanism of the organic PV device was discussed.

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Keywords: Organic photovoltaic device; Europium complex; Synthesis

Organic PV devices have attracted much attention due to their excellent properties such as light weight, low cost and compatibility with flexible substrates [1]. Most efforts, made in the past two decade, focused on improvement of power conversion efficiency (η_p) [2,3]. Unfortunately, η_p and the lifetime of organic PV devices are far from satisfactory. Both materials choice and device processing techniques are crucial for improving η_p [2,4]. Conjugated polymers, such as poly(phenylene vinylene) and its derivatives [5], have become the most interesting materials in the organic PV field, and in recent years attention has also been paid to some small molecules [5,6]. Chu et al. [7] have reported a PV device using yttrium complex as electron-acceptor with open circuit voltage (V_{oc}), short circuit current (I_{sc}), fill factor (FF) and η_p of 2.15 V, 46 μ A/cm², 0.3, 0.7%, respectively.

In order to explore highly efficient organic PV materials, herein we report the synthesis of an Eu(III) complex Eu(dibenzoylmethanate)₃(CPyBM) (Scheme 1). CPyBM containing 2-(2-pyridyl)benzimidazole fragment was selected as the second ligand, since it is thought to enhance the electron-transport capability of material [8], and the PV device using Eu(DBM)₃(CPyBM) as an electron-acceptor and electron-transport layer was fabricated simultaneously. The PV properties of Eu(DBM)₃(CPyBM) were investigated. The synthetic routes of the ligand CPyBM and the complex Eu(DB M)₃(CPyBM) are presented in Scheme 1.

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Eu(DBM)₃(CPYBM)

Scheme 1. Synthesis routes of the ligand CPyBM and the complex Eu(DBM)₃(CPyBM).

1. Experimental

9-(6-Bromohexyl)-9*H*-carbazole was prepared according to a literature method [8].

Synthesis of CPyBM. A mixture of 9-(6-bromohenxyl)-9*H*-carbazole (1.67 g, 5 mmol), 2-(2-pyridyl)benzimidazole (0.98 g, 5 mmol), NaOH (0.22 g, 5.5 mol) and DMF (30 mL) was stirred and heated at 120 °C for 15 h under N₂. It was subsequently poured into water, extracted with CH₂Cl₂. The resulting residue after removal of the solvent was purified by chromatography to give 1.8 g of product. Yield: 80%. mp: 50 °C. ¹H NMR (CDCl₃, δ ppm): δ 1.27–1.39 (m, 4H, alkyl protons), 1.68–1.85 (m, 4H, alkyl protons), 4.25–4.29 (t, 2H, J = 6.83 Hz, –NCH₂–), 4.77–4.81 (t, 2H, J = 7.46 Hz, –NCH₂–), 7.27 (t, 2H, J = 8.01 Hz, aromatic protons), 7.31 (t, 2H, J = 8.25 Hz, aromatic protons), 7.32 (t, 2H, J = 6.98 Hz, aromatic protons), 7.35 (d, 2H, J = 7.82 Hz, aromatic protons), 7.37 (d, 2H, J = 7.64 Hz, aromatic protons), 7.45 (d, 2H, J = 7.54 Hz, aromatic protons), 8.10 (d, 1H, J = 7.62 Hz, aromatic proton), 8.17 (t, 1H, J = 8.23 Hz, aromatic proton), 8.29 (t, 1H, J = 7.93 Hz, aromatic proton), 8.501 (d, 1H, J = 8.06 Hz, aromatic proton). EI-MS: m/z 444 (M⁺).

 $Eu(DBM)_3(CPyBM)$ was prepared according to a literature method [9]. Elemental analysis for $C_{75}H_{61}N_4O_6Eu$. Calcd: C, 71.14; H, 4.85; N, 4.42. Found: C, 71.20; H, 4.61; N, 4.34.

PV device with structure of indium tin oxide (ITO)/ploy(3,4-ethylenedioxy-thiophene):poly(styrenesulfonate) (PEDOT:PSS) (20 nm)/4,4′,4″-tris-[3-methylphenyl (phenyl) amino]triphenyl amine (*m*-MTDATA) (30 nm)/Eu(dibenzoylmethanate)₃ (CPyBM) (60 nm)/LiF (1 nm)/Al (100 nm) was fabricated as shown in Fig. 1. Eu(DBM)₃(CPYBM) and *m*-MTDATA were used as electron-acceptor and electron-donor, respectively. The ITO coated glass substrate was pre-coated with PEDOT:PSS, which acted as hole injection layer to lower the hole barrier at the ITO anode and increase the short circuit current. The light-state *I–V* characteristics of the PV device were measured under UV illumination at 365 nm of 1.6 mW/cm². The absorption spectra were measured with Shimadzu UV-3101PC spectrophotometer. Photocurrent response curves were recorded under 40 μA/cm² Xe lamp.

Al	
LiF (1 nm)	
Eu-complex (60 nm)	
m-MTDATA (30nm)	
PEDOT:PSS (20 nm)	
ITO	
GLASS	

Fig. 1. The configuration of the PV device.

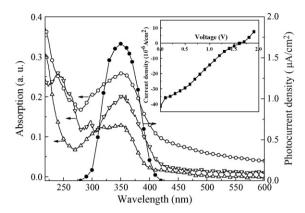


Fig. 2. The absorption spectra of Eu(DBM)₃(CPyBM) film (down triangle), *m*-MTDATA film (up triangle), *m*-MTDATA/Eu(DBM)₃(CPyBM) film (open circle), and photocurrent response of PV device (solid circle). Inset the *I*-V characteristics of the PV device.

2. Results and discussion

Fig. 2 exhibits the absorption spectra of m-MTDATA, Eu(DBM)₃(CPyBM) and m-MTDATA/Eu(DBM)₃(CPyBM) films, and the photovoltaic spectral response of the PV device. For the Eu(DBM)₃(CPyBM) film, the band at 297 nm is attributed to the absorption of carbazole fragment, the absorption band centering at 350 nm is assigned to π - π * transition of the DBM ligand. By compared the photocurrent response curve of the device with the absorption spectra of Eu(DBM)₃(CPyBM) and m-MTDATA films, it is found that their maximum peaks are nearly at the same position, and the total absorption of m-MTDATA/Eu(DBM)₃(CPyBM) films consists of Eu(DBM)₃(CPyBM) film and m-MTDATA film, indicating that the generation of photocurrent is attributed to the total absorption of both the m-MTDATA layer and the Eu(DBM)₃(CPYBM) layer. The most sensitive response wavelength of the device is about 310–390 nm, so this PV device containing Eu(DBM)₃(CPyBM) is suitable for fabricating photodetectors to detect UV light.

Both Eu(DBM)₃(CPyBM) and *m*-MTDATA have contributed to the PV effects of the device, and Eu(DBM)₃(CPyBM) should play electron-acceptor role, while *m*-MTDATA played electron-donor role in our PV device. Dissociations of the excitons must take place at the interface between Eu(DBM)₃(CPyBM) layer and *m*-MTDATA layer. The typical parameters, V_{oc} , I_{sc} , and FF of the PV device reached about 1.61 V, 41.5 μ A/cm², and 0.25, respectively, and η_p was about 1.04% under illumination with 365 nm UV light at 1.6 mW/cm², as shown in the inset of Fig. 2. These parameters are superior, compared with the previously reported PV device based on Eu(III) complex [10].

In conclusion, an Eu(III) complex Eu(DBM)₃(CPyBM) was synthesized and used as electron-acceptor and electron-transport layer in organic PV device. The typical parameters, $V_{\rm oc}$, $I_{\rm sc}$, and FF of the PV device reached about 1.61 V, 41.5 μ A/cm², and 0.25, respectively, and $\eta_{\rm p}$ was about 1.04% under illumination with 365 nm UV light at 1.6 mW/cm². Our results demonstrated that the PV performance based on lanthanide complex can be effectively improved by molecular design and superior device architecture.

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